

Analysis and Design of Two-Transformer Asymmetrical Half-Bridge Converter

Yi-Hsin Leu and Chern-Lin Chen, *Senior Member, IEEE*

Graduate Institute of Electronics Engineering & Department of Electrical Engineering
National Taiwan University, Taipei, Taiwan 106

Abstract- In this paper, the analysis of steady-state characteristics for two-transformer asymmetrical half-bridge converter is presented. Based on the mathematical derivations, ZVS condition of the power switches is quantized and a design procedure can be developed accordingly. The experimental results obtained from a 200kHz 24V/10A prototype converter with 92% efficiency are used to verify the analytical derivations.

I. INTRODUCTION

The asymmetrical duty cycle control method has been explored in detail for half-bridge flyback and forward topologies due to their inherent soft-switching phenomenon, low switch voltage stress, and high frequency operation [1]–[4]. The control method offers a manner of minimizing the turn on losses of the power switches by recycling the transformer leakage energy and subsequent reduction of the voltage and current surge of the output rectifiers. In single output applications, the asymmetrical half-bridge forward converter is superior to asymmetrical half-bridge flyback converter for its lower root-mean-square current of the output rectifiers. But, the converter is not suitable for operating within a wide input voltage range because the maximum allowable duty cycle is 50%.

A two-transformer asymmetrical half-bridge converter extending the allowable duty cycle to above 0.5 has been presented [5]. The simplified circuit of the converter is shown in Fig. 1. By tuning the different turn ratios of the transformers T_1 and T_2 , not only the maximum allowable duty cycle can be increased, but also the reverse voltage across the output rectifiers are more balanced [5]–[6]. In practical implementation, converter efficiency and soft-switching phenomena are greatly affected by the circuit parameters. In order to obtain the feasible circuit parameters, thorough analysis of the converter should be conducted.

This paper presents the complete design-oriented analysis of the two-transformer asymmetrical half-bridge converter. The converter operations are analyzed stagewise, and the characteristics of the key components are mathematically derived. Based on the derivative results, the ZVS condition of the power switches is quantized and a design procedure can be developed accordingly. Finally, a 24V/ 10A prototype converter operating at 200kHz is then built to verify the analytical derivations.

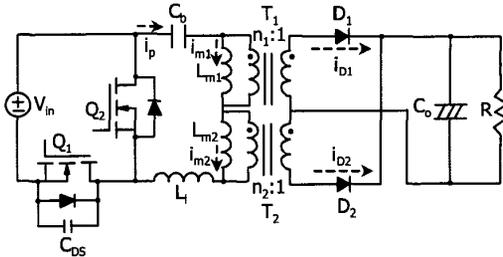


Fig. 1. Simplified schematic of the two-transformer asymmetrical half-bridge converter

II. PRINCIPLE OF OPERATION

Referring to Fig. 1, the power switches are driven with asymmetrical duty cycle. The inductor L_l represents the leakage inductor, which includes the leakage inductor of T_1 and T_2 . The capacitor C_{DS} represents the equivalent loop capacitor, which is the combination of the junction capacitor of the switches and the transformer intra winding capacitors. For simplifying the analysis of circuit operation, the following assumptions are made:

- the converter has reached a steady-state operation,
- sufficient energy is stored in L_l to completely discharge C_{DS} ,
- C_b is large enough so that the voltage variation of the capacitor is neglected, and
- forward voltage drop of the output rectifier is neglected.

In a switching period, operation of the studied converter can be divided into eight stages. Fig. 2 shows the switching topological states of the converter. The thick solid lines denote the conducting paths for each state. The corresponding waveforms on the key components are given in Fig. 3.

In order to show the transient phenomena clearly, the length of the time intervals $t_1 \sim t_3$ and $t_5 \sim t_7$ have been exaggerated.

Stage 1 ($t_0 \sim t_1$): At t_0 , switch Q_1 is turned on, and switch Q_2 is turned off. The voltage across L_{M1} is clamped at $N_1 V_O$, and the voltage across L_{M2} can be approximated as $V_{in} - V_C - N_1 V_O$. T_1 transfers energy to output through D_1 , and T_2 works as an inductor.

Stage 2 ($t_1 \sim t_2$): After Q_1 turned off at t_1 , C_{DS} is charged by the primary current i_p . Because C_{DS} is very small, the actual resonant charging manner is approximated as a linear charging characteristic. The voltage across Q_1 (V_{DS}) and L_{M2} is linearly increasing and decreasing, respectively.

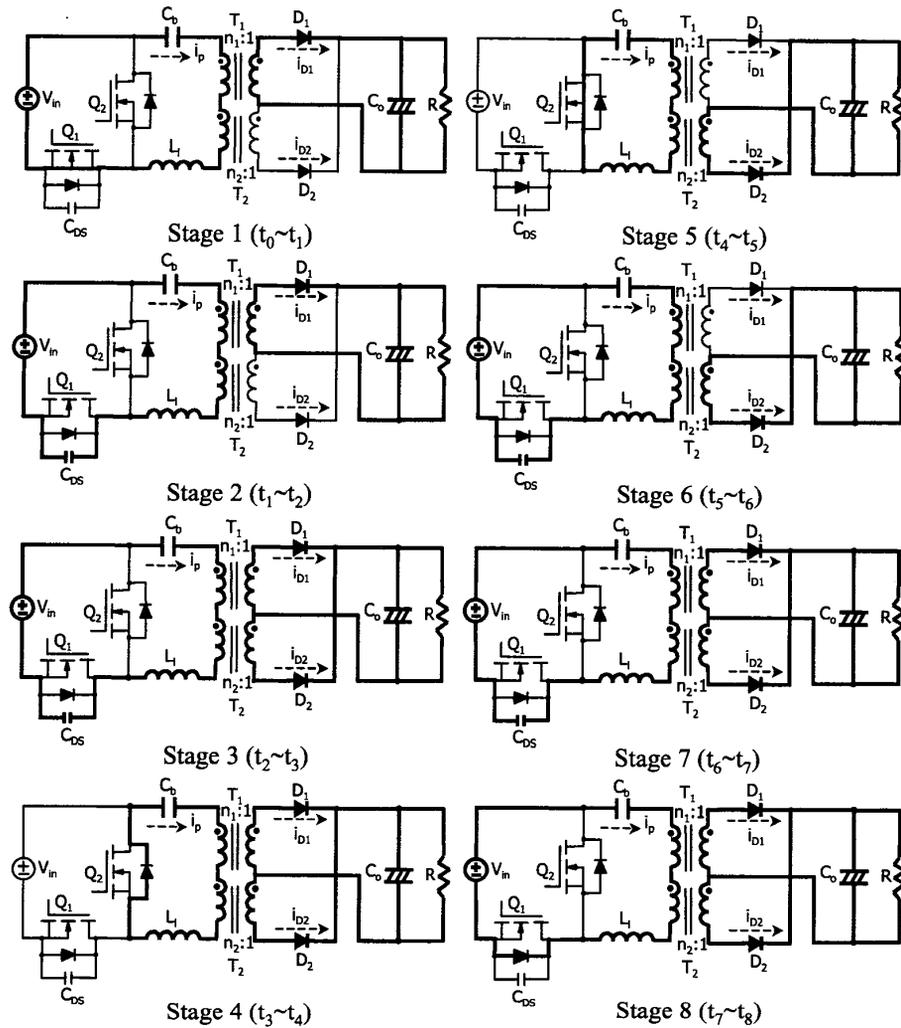


Fig. 2. Eight operational stages of the two-transformer asymmetrical half-bridge converter

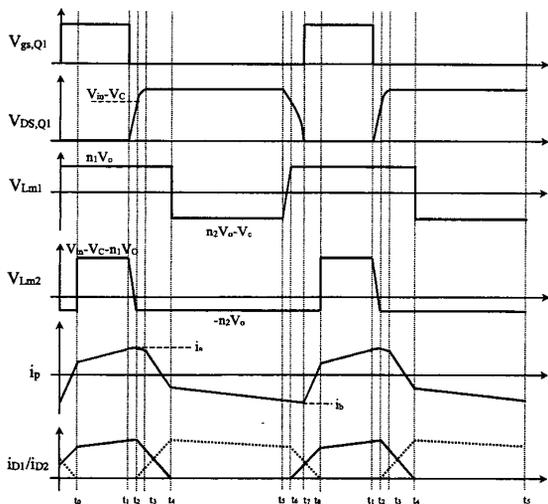


Fig. 3. The theoretical voltage and current waveforms on some key components

Stage 3 ($t_2 \sim t_3$): At t_2 , V_{DS} has increased to the point ($V_{DS} = V_{in} - V_C + N_2 V_O - N_1 V_O$) where the secondary voltage of transformer T_2 is sufficient to forward bias D_2 . The output rectifiers conduct simultaneously. L_1 and C_{DS} begin to resonate. The voltage $V_{DS}(t)$ and the primary current $i_p(t)$ are expressed by:

$$i_p(t) = i_a \cdot \cos[\omega_r(t - t_2)] \quad (1)$$

$$V_{DS}(t) = [V_{in} - V_C + (N_2 - N_1)V_O] + i_a \cdot Z_r \cdot \sin[\omega_r(t - t_2)] \quad (2)$$

where, $\omega_r = 1/\sqrt{L_1 \cdot C_{DS}}$, $Z_r = \sqrt{L_1 / C_{DS}}$

This stage ends when the voltage V_{DS} increases to V_{in} .

Stage 4 ($t_3 \sim t_4$): At t_3 , C_{DS} is charged to the point ($V_{DS} = V_{in}$) where the anti-parallel diode of Q_2 starts to conduct. In order for Q_2 to achieve ZVS, the device should be turned on before the primary current i_p reverses direction. The primary current i_p is ramped down linearly due to the

negative voltage $-V_C + (N_2 - N_1)V_O$ on the leakage inductor.

Stage 5 ($t_4 \sim t_5$): When i_p reaches i_{m1}^+ , the diode D_1 turns off. T_2 delivers power to output through D_2 , and T_1 plays an inductor role. The primary current i_p decreases linearly with the slope $(N_2 V_C - V_C)/L_l$.

Stage 6 ($t_5 \sim t_6$): After Q_2 is turned off at t_5 , the primary current i_p starts to discharge the capacitor C_{DS} . The voltage across Q_1 and L_{M1} is linearly decreasing and increasing, respectively. At t_6 , V_{DS} has decreased to the point $(V_{DS} = V_{in} - V_C + N_2 V_C - N_1 V_O)$ where the diode D_1 is forward biased. Again, D_1 and D_2 conduct simultaneously.

Stage 7 ($t_6 \sim t_7$): In this stage, L_l and C_{DS} resonate. The voltage $V_{DS}(t)$ and the primary current $i_p(t)$ are found as:

$$i_p(t) = i_b \cdot \cos[\omega_r(t - t_6)] \quad (3)$$

$$V_{DS}(t) = [V_{in} - V_C + (N_2 - N_1)V_O] + i_b \cdot Z_r \cdot \sin[\omega_r(t - t_6)] \quad (4)$$

Assuming the energy stored in L_l is larger than the energy stored in C_{DS} , V_{DS} is going to be discharged to zero. The anti-parallel diode of Q_1 starts to conduct.

Stage 8 ($t_7 \sim t_8$): It is the interval that switch Q_1 can be turned on under zero-voltage-switching condition. The primary current i_p is ramped up due to the positive voltage $V_{in} - V_C + (N_2 - N_1)V_O$ applies to the leakage inductor. At t_8 , i_p reaches i_{m2}^+ , D_2 turns off, and another switching cycle starts ($t_8 = t_0$).

III. DC ANALYSIS

The dc characteristics of the two-transformer asymmetrical half-bridge converter can be obtained in a simple method by ignoring the transition intervals. Therefore, only the stage 1 and stage 5 are investigated in dc analysis.

A. The static voltage transfer ratio

The static voltage transfer ratio (VTR) can be obtained by applying the equal-volt-seconds criterion to the two isolated transformers. The result can be formulated as:

$$\frac{V_O}{V_{in}} = \frac{D(1-D)}{N_1 D + N_2(1-D)} \quad (5)$$

From (5), the maximum value of the static VTR (M_{max}) and duty cycle (D_{max}) can be obtained:

$$M_{max} = \frac{1}{(\sqrt{N_1} + \sqrt{N_2})^2} \quad (6)$$

$$D_{max} = \frac{\sqrt{N_2}}{(\sqrt{N_1} + \sqrt{N_2})} \quad (7)$$

Fig. 4 shows the VTR curve as a function of the different turn ratios and duty cycle. Tuning the different turn ratios for transformer T_1 and T_2 , the maximum allowable duty cycle can be adjusted, but the maximum

value of VTR also affected. For example, if $N_2/N_1=1$, the $D_{max}=50\%$ and $M_{max}=0.25$. Changing the turn ratio into $N_2/N_1=2$, D_{max} can be augmented to 58.6%, but M_{max} decreased to 0.172.

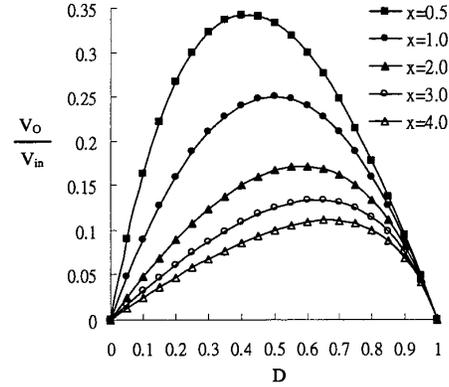


Fig. 4. Voltage transfer ratio for different turn ratios (where, $x=N_2/N_1$ is the different turn ratios coefficient)

B. Output rectifier voltage stress

Another advantage of modifying different turn ratios is balanced the reverse voltage stress of the output rectifier. The normalized reverse voltage in steady state across the output rectifiers can be calculated as follows:

$$\frac{V_{D1}(x)}{V_O} = \frac{1}{1 - D_{max}(x)} \quad (8)$$

$$\frac{V_{D2}(x, k)}{V_O} = \frac{1}{D_{min}(x, k)} \quad (9)$$

where, $k = V_{inmax}/V_{inmin}$ is the input voltage range coefficient.

The value of x dominates the reverse voltage across D_1 and the reverse voltage across D_2 is a function of x and k . Fig. 5 shows the normalized reverse voltage across the two output rectifiers with different x and k . By augmenting the value of x , the reverse voltage across D_2 can be reduced. And it just increases the reverse voltage across D_1 slightly.

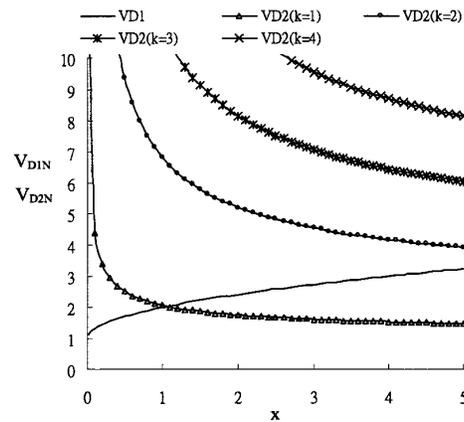


Fig. 5 Normalized reverse voltage across output rectifiers versus x for different input voltage range

C. Maximum magnetizing current of the transformers

When Q_1 is turned on, the magnetizing currents raise cause by the positive voltage applied to the magnetizing inductors. When Q_2 is turned on, these currents descend gradually. Taking the ac swing of the magnetizing current into account, the peak magnetizing current of T_1 (i_{m1}^+) and T_2 (i_{m2}^+) are:

$$i_{m2}^+ = \frac{I_o \cdot (1-D)}{N_1 D + N_2 (1-D)} + \frac{N_2 V_o}{2L_{m2} f_s} (1-D) \quad (10)$$

$$i_{m1}^- = \frac{-I_o \cdot D}{N_1 D + N_2 (1-D)} - \frac{N_1 V_o}{2L_{m1} f_s} D \quad (11)$$

D. Transformers Power Distribution

The power distribution of the two transformers in one switching period can be described as the following equation

$$P_{T1} = (I_{m2dc} - I_{m1dc}) \cdot D \cdot N_1 V_o = \frac{D}{x + D \cdot (1-x)} \cdot P_o \quad (12)$$

$$P_{T2} = (I_{m2dc} - I_{m1dc}) \cdot (1-D) \cdot N_2 V_o = \frac{x \cdot (1-D)}{x + D \cdot (1-x)} \cdot P_o \quad (13)$$

Where P_{T1} and P_{T2} represents the power distribution of T_1 and T_2 in one switching period, respectively. Fig. 6 shows the power distribution ratio of the two transformers (P_{T1}/P_{T2}) in one switching period with different turn ratios (x from 0.2 to 3) and duty cycle (D from 0.2 to 0.5). It is found that when the converter operates at the maximum duty cycle, the two transformers share the same power. The different turn ratios do not improve the uneven power distribution, but actually make it slightly worse.

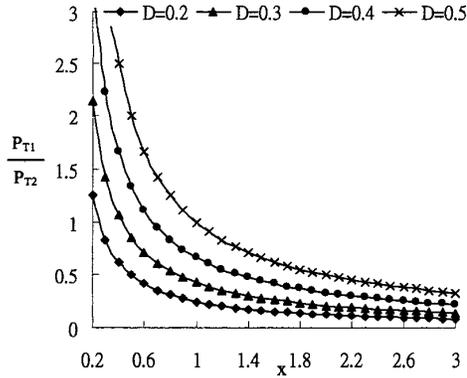


Fig. 6 The power distribution ratio of the transformers versus x for different duty cycle.

IV. ZERO-VOLTAGE SWITCHING ANALYSIS

As above-mentioned, there is a short transient interval between one MOSFET to be turned on and the other one has been turned off. Equations (2) and (4) represent the resonant behavior of the converter during the transition intervals. ZVS condition of the switch Q_2 and Q_1 can be

derived from (2) and (4). In order to achieve ZVS, the energy stored in L_l should be larger than the energy stored in C_{DS} . And it should satisfy the following equations.

$$L_l |i_p(t_2)|^2 \geq C_{DS} [V_c - (N_2 - N_1) V_o]^2 \quad (14)$$

$$L_l |i_p(t_6)|^2 \geq C_{DS} [V_{in} - V_c + (N_2 - N_1) V_o]^2 \quad (15)$$

Where $i_p(t_2)$ and $i_p(t_6)$ can be approximated to i_{m2}^+ and i_{m1}^- , respectively. Substituting (10) and (11) into (14) and (15), we can get:

$$L_l \geq C_{DS} \frac{(N_1 V_o)^2}{(1-D)^4} \left[I_r + \frac{N_2 V_o}{2L_{m2} f_s} \right]^2 \quad (16)$$

$$L_l \geq C_{DS} \frac{(N_2 V_o)^2}{D^4} \left[I_r + \frac{N_1 V_o}{2L_{m1} f_s} \right]^2 \quad (17)$$

$$I_r = \frac{I_o}{N_1 D + N_2 (1-D)} \quad (18)$$

Equations (16) and (17) formulate the minimum required value of the leakage inductance for reaching ZVS operation of the switches Q_2 and Q_1 , respectively. Obviously, the critical ZVS condition of the Q_1 is stricter than Q_2 . Therefore, the zero-voltage-switching of Q_1 should be drawn more attention in practical design. Moreover, a smaller magnetizing inductance is helpful to achieve ZVS operation of the switches.

V. DESIGN PROCEDURE

The design of significant circuit parameters can be derived from pondering over some design considerations. The procedure is described as follows.

A. Select the different turn ratios

In switching power supply, the conduction and switching loss of the output rectifier is the dominant loss component. In order to decrease these losses, the lower rating voltage rectifiers should be chosen such that a short recovery time and lower forward voltage drop diode can be used in practical application. Therefore, decreasing the reverse voltage across rectifiers is one of the most important trade offs for switching power supply design. In the modified asymmetrical half-bridge converter, the family of curves of normalized reverse voltage stress across the rectifiers with different input voltage range coefficient (k) and different turn ratios coefficient (x) has shown in Fig. 5. Base on the input voltage range and reverse voltage stress across the rectifiers, the different turn ratios can be selected. For example, if the input voltage range is unvaried ($k=1$), the different turn ratios must be chosen as $x=1$. In this case, the rectifiers accept the same reverse voltage stress. If $k=2$, in order to balance the reverse voltage across the rectifiers, the most suitable different turn ratios should be chosen as $x=2$.

B. Select the normal operation duty

In modified asymmetrical half-bridge converter, it is a

preferable choice to even the power distribution of the transformers for practical application. Fig. 6 shows the power distribution ratio of the two transformers with different turn ratios (x) and duty cycle (D). If the different turn ratios are chosen as $x=1$, the optimal design of the duty cycle is 0.5. But in practical design, the real D_{max} should be smaller than theoretical value such that there is enough margins to respond to load disturbances or duty cycle loss.

C. Select the transformer turn ratios

If we neglect the leakage inductance, the primary and secondary duty cycle is quite close, and the turn ratios of T_1 (N_1) can be determined from (5):

$$N_1 = \frac{D \cdot (1-D)}{[D+x \cdot (1-D)]} \cdot \frac{V_{in}}{V_o} \quad (19)$$

When taking the duty loss into consideration, the calculated value by (26) is always smaller than the desired. The realistic value can get by adding two or three turns of the calculated value. The turn ratios of T_2 is set as: $N_2=N_1 \cdot x$.

D. Determine the magnetizing inductors

The demands of the maximum flux density ($B_{T1,max}$, $B_{T2,max}$) of the transformers can be calculated as:

$$B_{T1,max} = \left[\frac{N_1 V_o D}{2W_1 A_{e1} f_s} + \frac{L_{m1} D I_r}{W_1 A_{e1}} \right] \cdot 10^8 \quad (20)$$

$$B_{T2,max} = \left[\frac{N_2 V_o (1-D)}{2W_3 A_{e2} f_s} + \frac{L_{m2} (1-D) I_r}{W_3 A_{e2}} \right] \cdot 10^8 \quad (21)$$

If the useable flux density of the material is B_{sat} , the maximum value of the magnetizing inductances can be derived from (20) and (21). And the magnetizing inductances should obey the following equations.

$$L_{m1} \leq \left[B_{sat} \cdot 10^{-8} - \frac{N_1 V_o D}{2W_1 A_{e1} f_s} \right] A_{e1} \cdot W_1 / I_r D \quad (22)$$

$$L_{m2} \leq \left[B_{sat} \cdot 10^{-8} - \frac{N_2 V_o (1-D)}{2W_3 A_{e2} f_s} \right] A_{e2} \cdot W_3 / I_r (1-D) \quad (23)$$

E. Design leakage inductance

The ZVS condition of S_1 is quantized as Equation (17). Fig. 7 shows the required value of the leakage inductance with different output current and duty cycle of the studied converter. If the ZVS range is selected, the minimum value of the required leakage inductor can be calculated from (17). Either a larger leakage inductance or a smaller magnetizing inductance is helpful to achieve ZVS of S_1 . If there is enough margins to respond to load disturbances or duty cycle loss, the leakage inductance should choose a larger value.

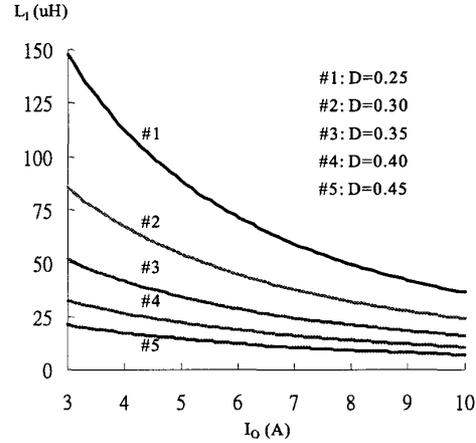


Fig. 7 Required leakage inductance for different range ZVS operation of S_1

VI. EXPERIMENTAL RESULTS

In order to characterize the soft switching phenomena of the modified asymmetrical half-bridge converter, a prototype was constructed to the specifications listed below:

input voltage: 400 VDC; output voltage: 24 VDC; maximum load current: 10 A; switching frequency: 200 kHz; normal operation duty cycle: 0.25; ZVS range: 80% to 100% load

Using the above-mentioned design procedure, the experimental converter was constructed using the following components:

- power switches Q_1 and Q_2 : Toshiba, 2SK2915;
- transformers T_1 : A_{e1} of core: 1cm^2 ; W_1 : 25 turns of $50 \times 0.1\text{mm}$; W_2 : 8 turns of Litz wire $50 \times 0.1\text{mm} \times 3$; L_{M1} : 150 μH ;
- transformer T_2 : A_{e2} of core: 1cm^2 ; W_3 : 25 turns of $50 \times 0.1\text{mm}$; W_4 : 8 turns of Litz wire $50 \times 0.1\text{mm} \times 3$; L_{M2} : 150 μH ;
- output rectifiers D_3 and D_4 : NIEC, C25P20F (FRD, $V_F=0.98\text{ V}$);
- leakage inductance L_f : 10 μH .

Under full load operation, the experimental waveforms on the key components are shown in Fig. 8. It is clear that ZVS operation of Q_1 is achieved because the device is turned on after the voltage across it falls to zero. In addition, the experimental result is in a good agreement with the theoretical analysis, as shown in Fig. 3.

The overall efficiency was measured under the different output current range, as shown in Fig. 9. The efficiency remains above 90% from 50% to full load.

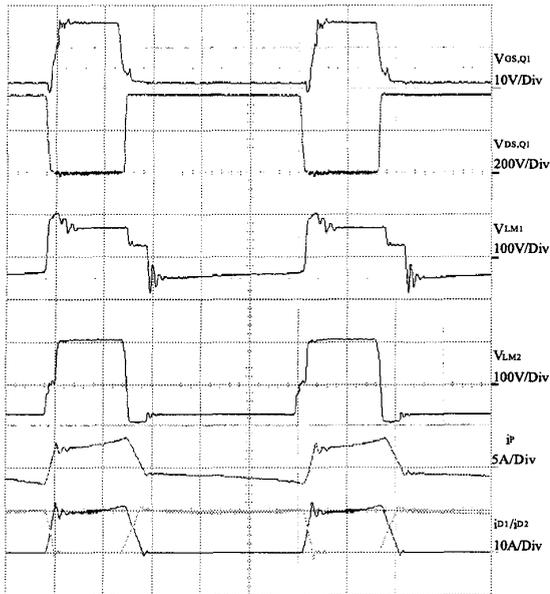


Fig. 8 Experimental waveforms on key components. (Time scale is 1 us/div).

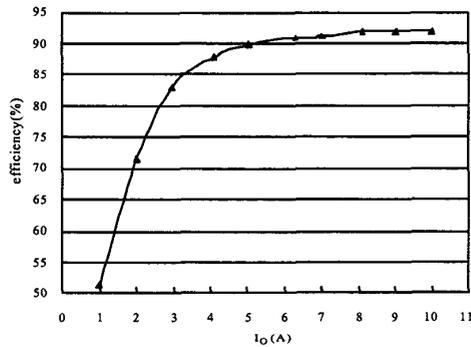


Fig. 9 Measured efficiency under different output current.

VII. CONCLUSION

The operational principles and DC characteristics have been analyzed for the two-transformer asymmetrical half-bridge converter. The results obtained by theoretical analysis can be utilized to quantize the ZVS condition of the power switches and predict the performance of the converter. The critical ZVS condition of Q_1 is stricter than Q_2 . In practical application, it is necessary to add an external inductor for achieving ZVS operation of Q_1 . Taking some practical trade-offs such as rectifier stress, ZVS operation, transformer power distribution etc into considerations, the design procedure is developed. According to the design rules, a prototype converter has been built. The experimental result is in a good agreement with the theoretical derivations.

REFERENCE

- [1]. C. P. Henze, D. S. Lo, J. Martin, and C. Hubert, "Zero-voltage resonant transition switching power converter," U.S. Patent 5 057 986, Oct. 1991.
- [2]. P. Imbertson and N. Mohan, "Asymmetrical Duty Cycle Permits Zero Switching Loss in PWM Circuits with No Conduction Loss Penalty," IEEE Trans. Industry Applications, Vol.29, No.1, Jan./Feb. 1993, pp. 121-125.
- [3]. S. Korotkov, V. Meleshin, R. Miftakhtudinov and S. Fraidlin, "Soft-Switched Asymmetrical Half-bridge DC/DC Converter: Steady-State Analysis: An Analysis Of Switching Processes," TELESCON, 1997, pp. 177-184.
- [4]. R. Oruganti, P. C. Heng, J. T. K. Guan, and L. A. Choy, "Soft-Switched DC/DC Converter with PWM Control," IEEE Trans. Power Electronics, Vol. 13, No. 1, Jan. 1998, pp. 102-114.
- [5]. R. Miftakhtudinov, A. Nemchinov, V. Meleshin and S. Fraidlin, "Modified Asymmetrical ZVS Half-Bridge DC-DC Converter," Applied Power Electronics Conference and Exposition, 1999, pp. 567-574.
- [6]. W. Chen, P. Xu and Fred C. Lee, "The Optimization of Asymmetrical Half Bridge Converter," Applied Power Electronics Conference and Exposition, 2001, pp. 703-707.